## NSN 5962-01-355-9500

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View Online at https://aerobasegroup.com/nsn/5962-01-355-9500 **Body Length:** 1.280 inches **Body Width:** Between 0.220 inches and 0.310 inches **Body Height:** 0.185 inches **Maximum Power Dissipation Rating:** 650.0 milliwatts **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **Features Provided:** Burn in and electrostatic sensitive and programmed **Inclosure Material:** Ceramic **Inclosure Configuration:** Dual-in-line **Output Logic Form:** Complementary-metal oxide-semiconductor logic **Input Circuit Pattern:** 21 input **Case Outline Source And Designator:** D-9 mil-m-38510 **Terminal Surface Treatment:** Solder **Voltage Rating And Type Per Characteristic:** -2.0 volts power source and 7.0 volts power source **Time Rating Per Chacteristic:** 50.00 nanoseconds access **Memory Device Type:** Pal **Test Data Document:** 96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.). **Terminal Type And Quantity:** 24 printed circuit Shelf Life: N/a **Unit Of Measure:** 

Demilitarization:

Yes - demil/mli

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